## NSN 5961-01-122-4101

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-122-4101 **Inclosure Material:** Metal **Overall Length:** 1.160 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 110.00 amperes forward current, average major and 125.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:**